

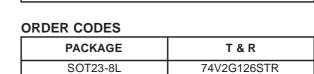
74V2G126

SOT323-8L

74V2G126CTR

DUAL BUS BUFFER (3-STATE)

- HIGH SPEED: $t_{PD} = 3.8 \text{ns}$ (TYP.) at $V_{CC} = 5 \text{V}$
- LOW POWER DISSIPATION: $I_{CC} = 1\mu A(MAX.)$ at $T_A=25^{\circ}C$
- HIGH NOISE IMMUNITY: V_{NIH} = V_{NIL} = 28% V_{CC} (MIN.)
- POWER DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE: $|I_{OH}| = I_{OL} = 8\text{mA (MIN)}$ at $V_{CC} = 4.5\text{V}$
- BALANCED PROPAGATION DELAYS: t_{PLH} ≅ t_{PHL}
- OPERATING VOLTAGE RANGE: V_{CC}(OPR) = 2V to 5.5V
- IMPROVED LATCH-UP IMMUNITY



SOT23-8L

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DESCRIPTION

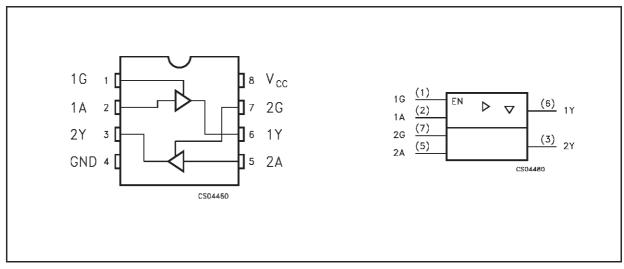
The 74V2G126 is an advanced high-speed CMOS DUAL BUS BUFFER fabricated with sub-micron silicon gate and double-layer metal wiring C²MOS tecnology.

3-STATE control input nG has to be set LOW to place the output into the high impedance state. Power down protection is provided on all inputs and outputs and 0 to 7V can be accepted on

inputs with no regard to the supply voltage. This device can be used to interface 5V to 3V systems and it is ideal for portable applications like personal digital assistant, camcorder and all battery-powered equipment.

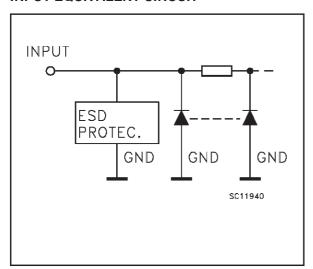
All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



November 2001 1/11

INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 7	1G, 2G	Output Enable Inputs
2, 5	1A, 2A	Data Inputs
3, 6	2Y, 1Y	Data Outputs
4	GND	Ground (0V)
8	V _{CC}	Positive Supply Voltage

TRUTH TABLE

Α	G	Y
X	L	Z
L	Н	L
Н	Н	Н

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage (see note 1)	-0.5 to +7.0	V
Vo	DC Output Voltage (see note 2)	-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	- 20	mA
I _{OK}	DC Output Diode Current	- 20	mA
Io	DC Output Current	± 25	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 50	mA
T _{stg}	Storage Temperature	-65 to +150	°C
TL	Lead Temperature (10 sec)	260	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	2 to 5.5	V
V _I	Input Voltage	0 to 5.5	V
Vo	Output Voltage (see note 1)	0 to 5.5	V
Vo	Output Voltage (see note 2)	0 to V _{CC}	V
T _{op}	Operating Temperature	-55 to 125	°C
dt/dv	Input Rise and Fall Time (note 3) (V_{CC} = 3.3 \pm 0.3V) (V_{CC} = 5.0 \pm 0.5V)	0 to 100 0 to 20	ns/V ns/V

¹⁾ Vcc=0V or nG=Vcc (Output in High Impedence state)
2) High or Low State
3) V_{IN} from 30% to 70% of V_{CC}

X: "H" or "L" Z: High Impedance

DC SPECIFICATION

		Т	est Condition		Value						
Symbol	Parameter	V _{CC}		T _A = 25°C -40 to				85°C	85°C -55 to 125°C		Unit
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
V _{IH}	High Level Input	2.0		1.5			1.5		1.5		
	Voltage	3.0 to 5.5		0.7V _{CC}			0.7V _{CC}		0.7V _{CC}		V
V _{IL}	Low Level Input	2.0				0.5		0.5		0.5	
	Voltage	3.0 to 5.5				0.3V _{CC}		0.3V _{CC}		0.3V _{CC}	V
V _{OH}	High Level Ouput	2.0	I _O =-50 μA	1.9	2.0		1.9		1.9		
	Voltage	3.0	I _O =-50 μA	2.9	3.0		2.9		2.9		
		4.5	I _O =-50 μA	4.4	4.5		4.4		4.4		V
		3.0	I _O =-4 mA	2.58			2.48		2.4		
		4.5	I _O =-8 mA	3.94			3.8		3.7		
V _{OL}	Low Level Output	2.0	I _O =50 μA		0.0	0.1		0.1		0.1	
	Voltage	3.0	I _O =50 μA		0.0	0.1		0.1		0.1	
		4.5	I _O =50 μA		0.0	0.1		0.1		0.1	V
		3.0	I _O =4 mA			0.36		0.44		0.55	
		4.5	I _O =8 mA			0.36		0.44		0.55	
I _{OZ}	High Impedance Output Leakage Current	5.5	$V_I = V_{IH} \text{ or } V_{IL}$ $V_O = 5.5 \text{ or GND}$			±0.25		± 2.5		± 5	μА
I _I	Input Leakage Current	0 to 5.5	V _I = 5.5V or GND			± 0.1		± 1		± 1	μА
I _{OPD}	Power down Output Leakage Current	0	V _O = 5.5			0.5		5		10	μА
I _{CC}	Quiescent Supply Current	5.5	$V_I = V_{CC}$ or GND			1		10		20	μА

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

		Test Condition			Value							
Symbol Parameter	v _{cc}	CL		Т	A = 25°	С	-40 to	85°C	-55 to 125°C		Unit	
		(V)	(pF)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
t _{PLH}	Propagation Delay	3.3 ^(*)	15			5.1	7.5	1.0	8.5	1.0	9.5	
t _{PHL}	Time	3.3 ^(*)	50			5.6	8.0	1.0	9.5	1.0	10.5	no
		5.0 ^(**)	15			3.8	5.5	1.0	6.5	1.0	7.5	ns
		5.0 ^(**)	50			4.3	6.5	1.0	7.5	1.0	8.5	
t _{PLZ}	Output Disable	3.3 ^(*)	15	$R_L = 1 \text{ K}\Omega$		5.4	8.0	1.0	9.0	1.0	10.0	
t _{PHZ}	Time	3.3 ^(*)	50	$R_L = 1 \text{ K}\Omega$		7.9	11.5	1.0	12.5	1.0	13.5	no
		5.0 ^(**)	15	$R_L = 1 K\Omega$		3.6	5.0	1.0	6.0	1.0	7.0	ns
		5.0 ^(**)	50	$R_L = 1 \text{ K}\Omega$		5.1	7.0	1.0	8.0	1.0	9.0	
		3.3 ^(*)	15	$R_L = 1 \text{ K}\Omega$		5.4	7.6	1.0	9.5	1.0	10.5	
t _{PZL}	Output Enable	3.3 ^(*)	50	$R_L = 1 \text{ K}\Omega$		5.9	8.5	1.0	10.0	1.0	11.0	ns
t _{PZH}	Time	5.0 ^(**)	15	$R_L = 1 K\Omega$		3.7	5.9	1.0	7.0	1.0	8.0	
		5.0 ^(**)	50	$R_L = 1 \text{ K}\Omega$		4.1	6.5	1.0	7.5	1.0	8.5	

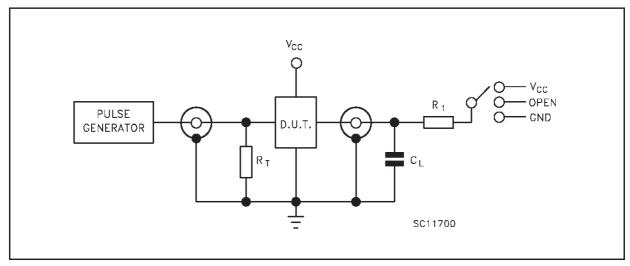
^(*) Voltage range is 3.3V ± 0.3V (**) Voltage range is 5.0V ± 0.5V

CAPACITIVE CHARACTERISTICS

	Test Condition		Value							
Symbol	Parameter		Ţ	A = 25°	С	-40 to	85°C	-55 to	125°C	Unit
			Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
C _{IN}	Input Capacitance			4	10		10		10	pF
C _{OUT}	Output Capacitance			6						pF
C _{PD}	Power Dissipation Capacitance (note 1)			14						pF

¹⁾ C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/2$

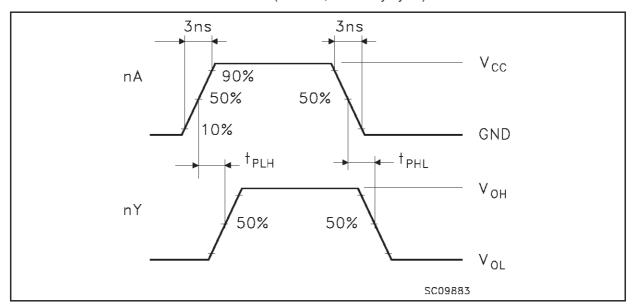
TEST CIRCUIT TEST CIRCUIT



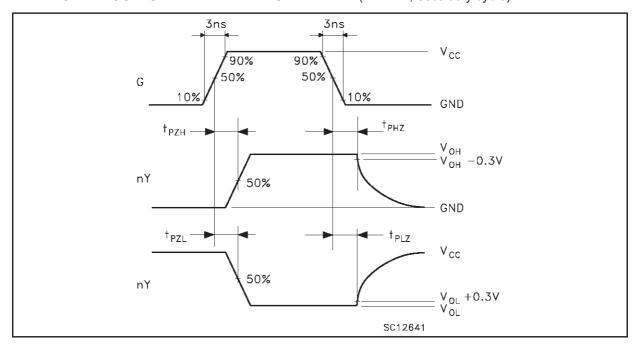
TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	V _{CC}
t _{PZH} , t _{PHZ}	GND

 C_1 =15/50pF or equivalent (includes jig and probe capacitance) R1 = 1K Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

WAVEFORM 1: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)

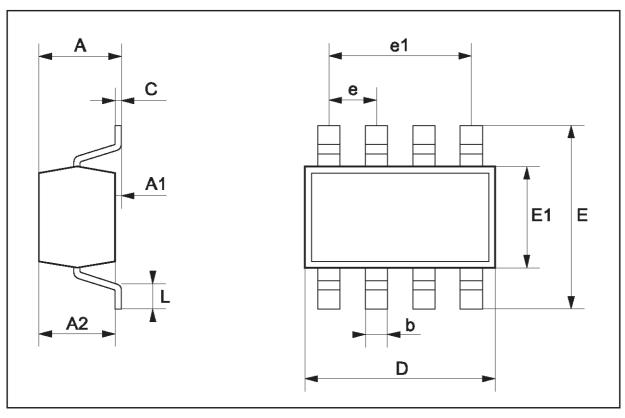


WAVEFORM 2: OUTPUT ENABLE AND DISABLE TIME (f=1MHz; 50% duty cycle)



SOT23-8L MECHANICAL DATA

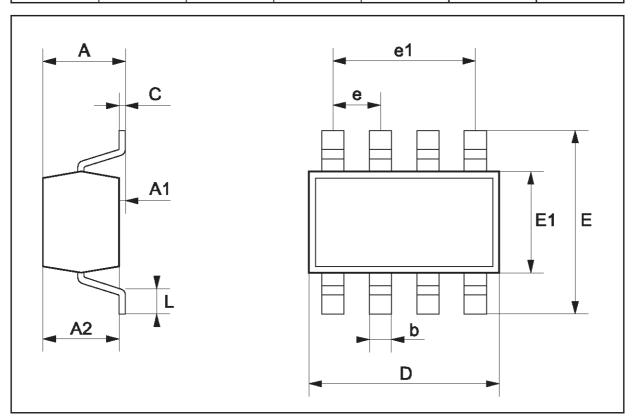
DIM		mm.		mils			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	0.90		1.45	35.4		57.1	
A1	0.00		0.15	0.0		5.9	
A2	0.90		1.30	35.4		51.2	
b	0.22		0.38	8.6		14.9	
С	0.09		0.20	3.5		7.8	
D	2.80		3.00	110.2		118.1	
E	2.60		3.00	102.3		118.1	
E1	1.50		1.75	59.0		68.8	
е	0	.65			25.6		
e1		1.95			76.7		
L	0.35		0.55	13.7		21.6	



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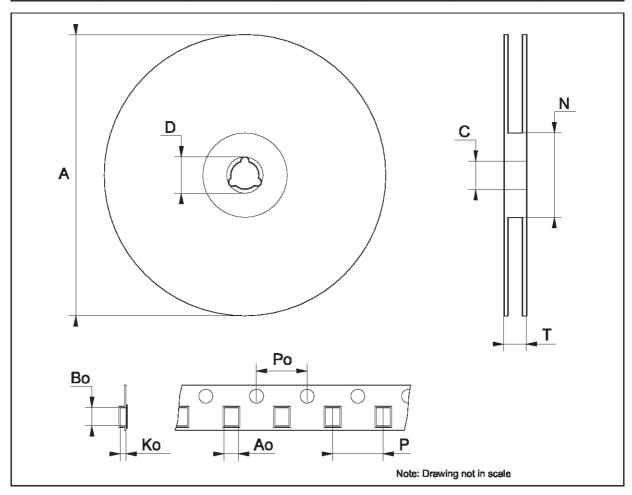
SOT323-8L MECHANICAL DATA

DIM		mm.		mils			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	0.80		1.10	31.5		43.3	
A1	0.00		0.10	0.0		3.9	
A2	0.80		1.00	31.5		34.9	
b	0.13		0.28	5.1		11.0	
С	0.10		0.18	3.9		7.1	
D	1.80		2.20	70.9		86.6	
E	1.80		2.40	70.9		94.5	
E1	1.15		1.35	45.3		53.1	
е		0.5			19.7		
e1		1.5			59.0		
L	0.10		0.30	3.9		11.8	



Tape &	Reel SOT23-xL	MECHANICAL	DATA
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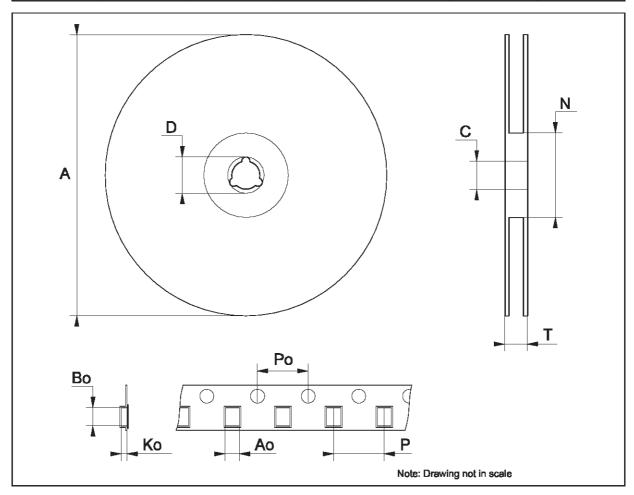
DIM		mm.				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			180			7.086
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			14.4			0.567
Ao	3.13	3.23	3.33	0.123	0.127	0.131
Во	3.07	3.17	3.27	0.120	0.124	0.128
Ko	1.27	1.37	1.47	0.050	0.054	0.0.58
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	3.9	4.0	4.1	0.153	0.157	0.161



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Tape & Reel SOT323-xL MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А	175	180	185	6.889	7.086	7.283
С	12.8	13	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	59.5	60	60.5		2.362	
Т			14.4			0.567
Ao		2.25			0.088	
Во		2.7			0.106	
Ko		1.2			0.047	
Ро	3.98	4	4.2	0.156	0.157	0.165
Р	3.98	4	4.2	0.156	0.157	0.165



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